

Switchmode Full Plastic Single Ultra-fast Power Rectifiers

Designed for use in switching power supplies, inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- * High Surge Capacity
- *Low Power Loss, High efficiency
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage, High Current Capability
- * High-Switching Speed Recovery Time
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- * In compliance with EU RoHs directives





MAXIMUM RATINGS

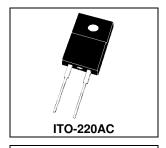
Characteristic	Symbol	URAF3040	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	400	V
RMS Reverse Voltage	V _{R(RMS)}	280	V
Average Rectifier Forward Current	I _{F(AV)}	30	Α
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	30	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I _{FSM}	200	А
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150	$^{\circ}$ C

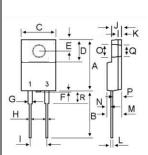
ELECTRICAL CHARACTERISTICS

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Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 30 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 30 \text{ Amp } T_C = 125^{\circ}C$)	V _F		1.17 0.97	1.50	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		0.05 20	10	uA
Reverse Recovery Time ($I_F = 0.5 A$, $I_R = 1.0$, $I_{rr} = 0.25 A$)	Trr		37	50	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C _P		280		₽F

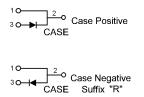
ULTRA FAST RECTIFIERS

30 AMPERES **400 VOLTS**





DIM	MILLIMETERS			
DIM	MIN	MAX		
Α	14.80	16.10		
В	12.65	14.40		
С	9.70	10.36		
D	4.60	6.80		
E	2.50	3.50		
F		2.00		
G	0.90	1.45		
Н	0.50	0.90		
- 1	4.80	5.40		
J	2.34	3.30		
K	0.55	1.30		
L	0.36	0.80		
M	4.20	4.90		
N	1.10	1.80		
0	2.90	3.50		
Р	2.30	3.15		
Q	2.90	3.50		
R	2.80	4.85		





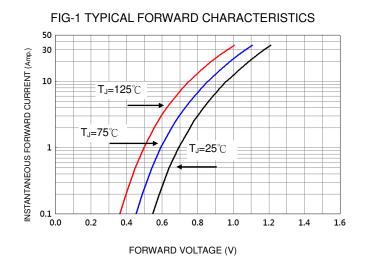
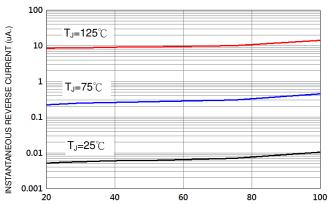
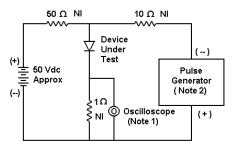


FIG-2 TYPICAL REVERSE CHARACTERISTICS



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)



- 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

FIG-3 FORWARD CURRENT DERATING CURVE

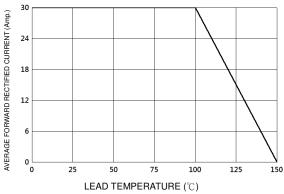


FIG-4TYPICAL JUNCTION CAPACITANCE

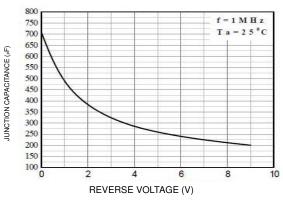
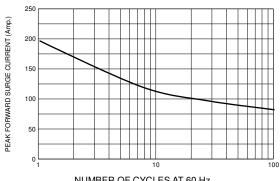
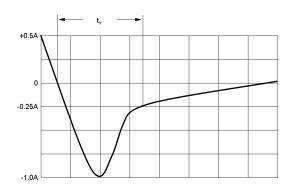


FIG-5PEAK FORWARD SURGE CURRENT



NUMBER OF CYCLES AT 60 Hz



Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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